

APTM100H45FT3G

APTM100H45FT3G Information

Heisener.com

Part Number APTM100H45FT3G

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description MOSFET 4N-CH 1000V 18A SP3

Package SP3

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
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Request a Quote



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









APTM100H45FT3G Specifications

	Report errors?
Supplier Device Package	SP3
Package / Case	SP3
Mounting Type	Chassis Mount
Operating Temperature	-40°C ~ 150°C (TJ)
Power - Max	357W
Input Capacitance (Ciss) (Max) @ Vds	4350pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	154nC @ 10V
Vgs(th) (Max) @ Id	5V @ 2.5mA
Rds On (Max) @ Id, Vgs	540 mOhm @ 9A, 10V
Current - Continuous Drain (Id) @ 25°C	18A
Drain to Source Voltage (Vdss)	1000V (1kV)
FET Feature	Standard
FET Type	4 N-Channel (H-Bridge)
Series	-
Package	SP3
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APTM100H45FT3G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

APTM100H45FT3G Payment Methods



















APTM100H45FT3G Shipping Methods













If you have any question about APTM100H45FT3G, please do not hesitate to contact us!

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